



DMP31D7LW

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
	0.9Ω @ V _{GS} = -10V	-0.52A
-30V	1.7Ω @ V _{GS} = -4.5V	-0.38A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC converters
- Load switches
- Power management functions

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

P-CHANNEL ENHANCEMENT MODE MOSFET

Mechanical Data

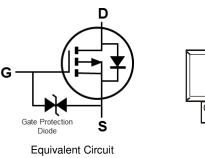
- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)





SOT323

Top View



Pin-Out Top View

D

Ordering Information (Note 4)

Part Number	Backaga	Packing		
	Package	Qty.	Carrier	
DMP31D7LW-7	SOT323	3000	Tape & Reel	
DMP31D7LW-13	SOT323	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

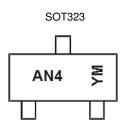
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:



Marking Information



 $\begin{array}{l} AN4 = Product \ Type \ Marking \ Code \\ YM = Date \ Code \ Marking \\ Y \ or \ \overline{Y} = Year \ (ex: \ J = 2022) \\ M = Month \ (ex: \ 9 = September) \end{array}$

Date Code Kev

Year	2019		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	G		J	К	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-30	V		
Gate-Source Voltage	VGSS	±20	V		
	Steady	TA = +25°C		-0.38	٨
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	State	$T_A = +70^{\circ}C$	ID	-0.3	A
Maximum Body Diode Forward Current (Note 5)	ls	-0.42	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%))		ldм	-2.6	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	0.29	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	424	°C/W
Total Power Dissipation (Note 5)		PD	0.37	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	334	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

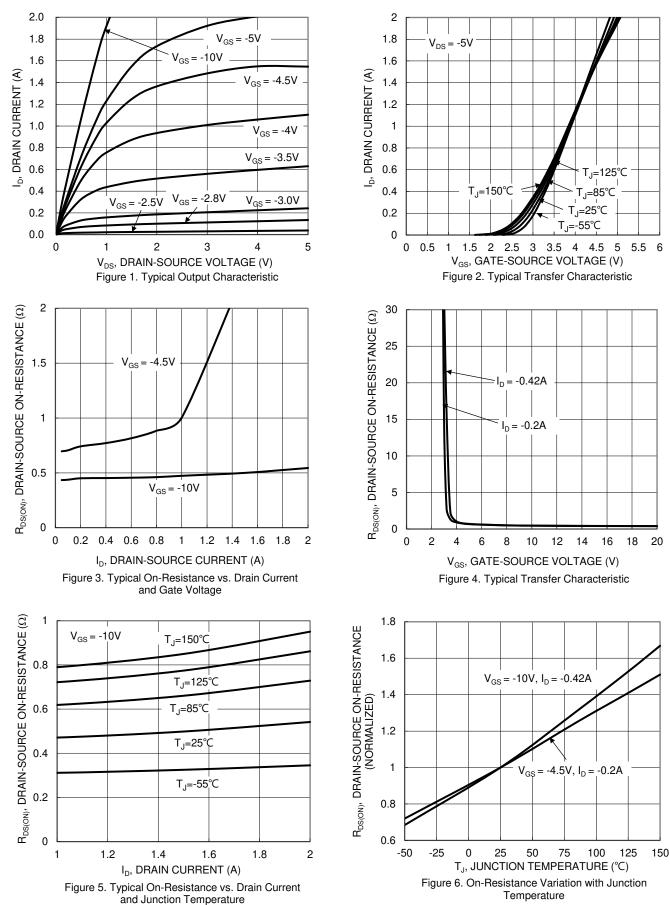


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	$V_{GS} = 0V, I_{D} = -250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS		_	-1	μA	V _{DS} = -24V, V _{GS} = 0V
Gate-Source Leakage		_	—	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	-1	-2.0	-2.6	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Proven		0.45	0.9	Ω	$V_{GS} = -10V, I_D = -0.42A$
Static Drain-Source On-Resistance	R _{DS(ON)}		0.74	1.7	12	$V_{GS} = -4.5V, \ I_D = -0.2A$
Diode Forward Voltage	VSD		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -0.23A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		19	_	pF	
Output Capacitance	Coss	_	16	—	pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		3	—	pF	
Gate Resistance	Rg		729	—	Ω	$V_{DS} = V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg		0.36	—	nC	
Gate-Source Charge	Qgs		0.1	—	nC	VGS = -4.5V, VDS = -10V
Gate-Drain Charge	Q _{gd}		0.1	—	nC	
Turn-On Delay Time	t _{D(ON)}		30	_	ns	
Turn-On Rise Time	tR		74	_	ns	$V_{DD} = -10V, V_{GS} = -4.5V$
Turn-Off Delay Time	tD(OFF)	_	28	_	ns	$R_{L} = 47\Omega, R_{g} = 10\Omega$ $D_{D} = -200 \text{mA}$
Turn-Off Fall Time	tF	_	31	—	ns	

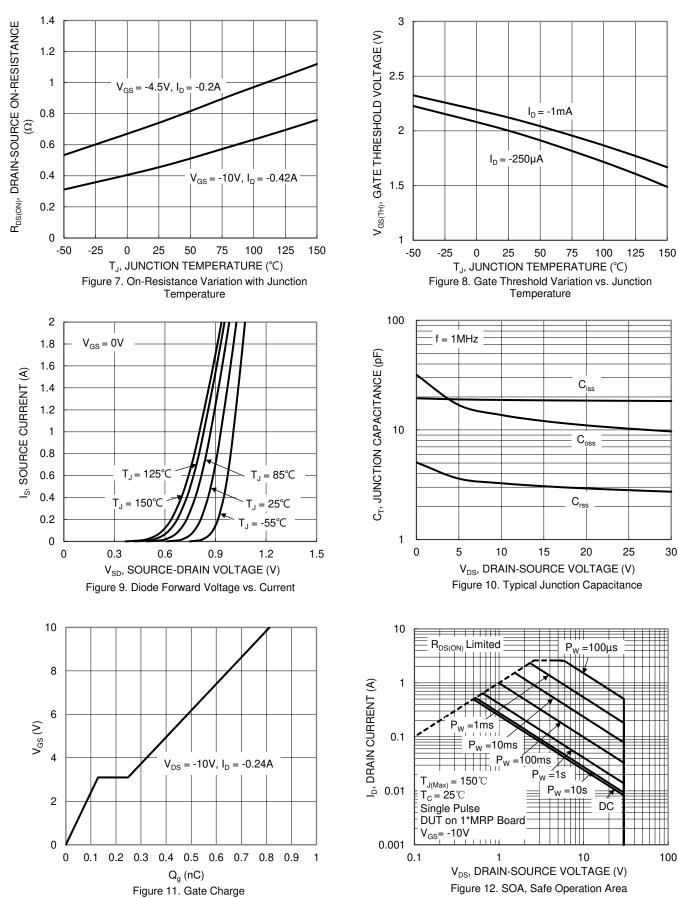
 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



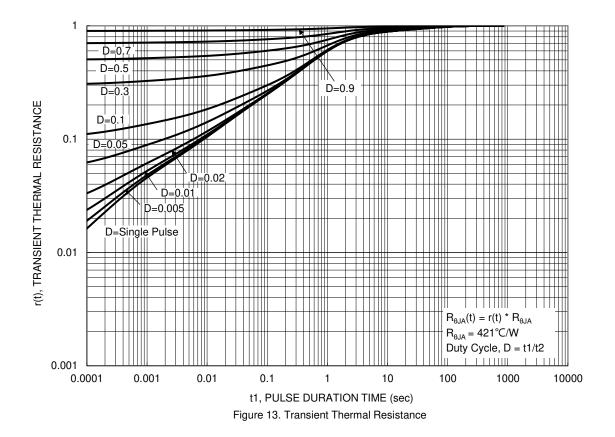




30



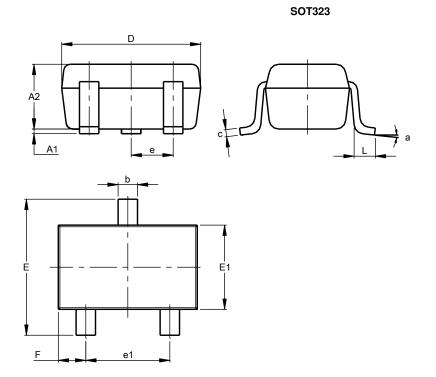






Package Outline Dimensions

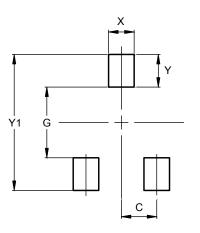
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
e1	1.20	1.20 1.40 1.30						
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions i	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

SOT323



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